### **Transmissive Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Wide operating temperature range (- 55°C to +100°C)
- 0.50 in.(12.7 mm) high optical axis position
- 0.375 in.(9.52 mm) slot width



#### DESCRIPTION

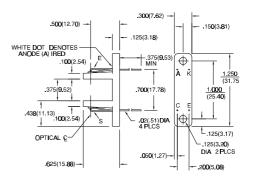
The HOA1877 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1877-001, - 002) or photodarlington (HOA1877-003) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1877 series has a 0.050 in.(1.27 mm) dia. detector aperture and employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.



Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_049.cdr



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#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	l <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1877-001, -002 HOA1877-003	V <sub>(BR)</sub> ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current HOA1877-001, -002 HOA1877-003	Iceo			100 250	nA	V <sub>CE</sub> =10 V I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1877-001 HOA1877-002 HOA1877-003	Ic(on)	0.1 0.5 1.5			mA	V <sub>CE</sub> =5 V I <sub>F</sub> =30 mA
Collector-Emitter Saturation Voltage HOA1877-001 HOA1877-002 HOA1877-003	VCE(SAT)			0.4 0.4 1.1	V	I <sub>F</sub> =30 mA I <sub>C</sub> =10 μA I <sub>C</sub> =60 μA I <sub>C</sub> =190 μA
Rise And Fall Time HOA1877-001, -002 HOA1877-003	t <sub>r</sub> , t <sub>f</sub>		15 75		μs	$V_{CC}$ =5 V, $I_{C}$ =1 mA $R_{L}$ =1000 $\Omega$ $R_{L}$ =100 $\Omega$

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

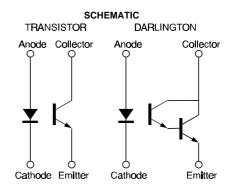
Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

IR EMITTER

Power Dissipation 75 mW <sup>(1)</sup>
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 VPower Dissipation75 mW (1)75 mW (1)Collector DC Current30 mA30 mA

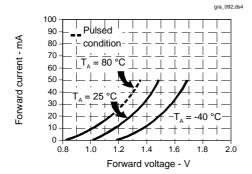


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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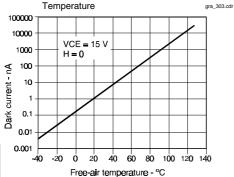
### **Transmissive Sensor**

IRED Forward Bias Characteristics



Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = = Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms

Dark Current vs Fig. 3 Temperature



Collector Current vs Fig. 4 Ambient Temperature gra\_095.ds4 Normalized collector current 1.0 0.4 0.2 0.0 75 -50 0 25 50 100 Free-air temperature - °C

All Performance Curves Show Typical Values

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